HOLLOW CATHODE LAMPS



OVERVIEW

Atomic absorption spectroscopy (or AAS) in its modern form came from principles developed by Australian physicist Dr. A. Walsh in 1955. Atomic absorption spectroscopy is ideal analysis for minute quantities of metallic elements because its operating principle and analysis method offer relatively simple measurement with high accuracy.

Hamamatsu provides a full line of hollow cathode lamps developed by our discharge tube manufacturing technology accumulated over long years of experience. These lamps provide the sharp, high-purity spectral lines essential for high accuracy measurement.

■TYPE OF HOLLOW CATHODE LAMPS

Hollow cathode lamps consist of single-element lamps and multi-element lamps. Single-element lamps are usually superior to multi-element lamps in absorption sensitivity and analytical line radiant intensity. Although multi-element lamps offer the advantage of simultaneous determination of multiple elements, their cathode composition must be determined by taking the properties of the metals to combine fully into account. Because of that, fabricating cathodes from an optional combination of elements is not possible.

APPLICATIONS

- Atomic absorption spectrophotometers
- Atomic fluorescence spectrophotometers
- Multi-element analyzers
- Environmental analytical instruments

CONSTRUCTION

As shown in Figure 1, a hollow cathode lamp is constructed with a bulb having a window (① in Figure 1) made of synthetic silica or UV glass or borosilicate glass, and into which a hollow cathode (⑥ in Figure 1) and a ring-shaped anode (④ in Figure 1) are assembled.

Noble gas is also sealed inside at a pressure of several hundred pascals. The hollow cathode is made of a single element or alloy of the element to be analyzed to ensure sharp analytical lines with an absolute minimum of interfering spectral components.

Figure 1: Construction of hollow cathode lamp

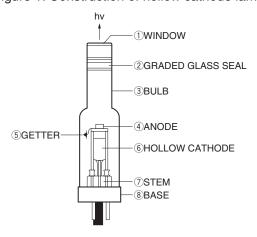
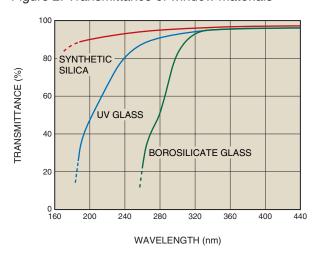


Figure 2: Transmittance of window materials



OPERATING PRINCIPLE

The hollow cathode lamp is a type of glow discharge tube that uses a hollow cathode to enhance the emission intensity. Compared to parallel plate electrodes, using a hollow cathode increases the current density by more than 10 times and this is accompanied by a significant increase in light emission intensity and a lower voltage drop in the lamp. This is known as the hollow cathode effect (or hollow effect).

When a voltage is applied across the electrodes of a hollow cathode lamp, electrons pass from the interior of the cathode to the cathode-fall region and flow through the negative glow region toward the anode. This causes ionization of the gas within the lamp through inelastic collisions with the gas. Positive ions generated by the gas ionization are accelerated by the electric field and collide with the cathode surface. The kinetic energy of ion impact causes the cathode materials to sputter (or fly) away from the cathode surface in the form of an atomic vapor.

Meanwhile electrons are accelerated by the electric field toward the anode. The electrons collide with the ground-state metal atoms being diffused and excite the metal atoms. The excited metal atoms return to the ground state again in an extremely short transition time of about 10-8 seconds. At this point, monochromatic light characteristic of those atoms is emitted at an energy corresponding to the energy difference between the excited state and the ground state.

This transition of electrons occurs not only in the target element for quantitative analysis but also in other elements of the cathode materials, causing a variety of energy transitions to occur. So, in a wide spectral range, many spectral lines of those elements and the gas can be observed. Transition metal elements such as Ni, Co and Fe in particular result in an extremely large number of spectral lines.

LINEUP OF HOLLOW CATHODE LAMPS

●L233 SERIES (38 mm DIA.): SINGLE-ELEMENT HOLLOW CATHODE LAMPS (66 LAMPS) ①

Element number (suffix) line (nm) Type	. Max.
Ag Silver 47 -47NB(AG) 338.28 10	
AI AIUIIIIIIIIII 13 -13ND(AL) 396.15 10	
A3 Alseliic 33 -3311Q(A3) 197.20 10	12
Ad Gold 79 -79NQ(AO) 267.59 10	16
B Boron 5 -5NQ(B) 249.68* 10 10 10 10 10 10 10 10 10 10 10 10 10	20
Ba Ballulli 30 -30NB(BA) 10	20
Be Beryllium 4 -4NQ(BE) 234.86 * 10	20
Bi Bismuth 83 -83NQ(BI) 223.06 * 10	12
Ca Calcium 20 -20NU(CA) 422.67 * 10	18
Cd Cadmium 48 -48NQ(CD) 228.80 * 5	12
Co Cobalt 27 -27NU(CO) 240.73 * 10	20
Cr Chromium 24 -24NB(CR) 357.87 * 425.44 10	20
Cs Caesium 55 -55NB(CS) 852.11 * 10	20
Cu Copper 29 -29NB(CU) 324.75 * 10	20
Dy Dysprosium 66 -66NB(DY) 404.59 * 421.17 15	15
Er Erbium 68 -68NB(ER) 400.79 * 15	15
Eu Europium 63 -63NB(EU) 459.40 15	15
Fe Iron 26 -26NU(FE) 248.33 * 10	20
Ga Gallium 31 -31NU(GA) 287.42 294.36 * 4	6
Gd Gadolinium 64 -64NB(GD) 407.87 422.58 * 12	12
Ge Germanium 32 -32NU(GE) 265.16 * 10	20
Hf Hafnium 72 -72NU(HF) 286.64 * 20	25
Hg Mercury 80 -80NU(HG) 253.65 * 4	6
Ho Holmium 67 -67NB(HO) 410.38 * 15	20
1 1 1 303 94 * 40	15
In Indium 49 -49NB(IN) 325.61 10	20
K Potassium 19 -19NB(K) 766.49 * 769.90 10	15
La Lanthanum 57 -57NB(LA) 357.44 10	20
Li Lithium 3 -3NB(LI) 610.36 (670.78) 10 Lu Lutetium 71 -71NB(LU) 328.17 (331.21) 15	20
Lu Lutetium 71 -71NB(LU) 328.17 15	15
Mg Magnesium 12 -12NU(MG) 285.21 * 10	18
Mn Manganese 25 -25NU(MN) 279.48 * 10	20
Mo Molybdenum 42 -42NB(MO) 313.26 * 10	
Na Sodium 11 -11NB(NA) 589.00 * 10	15
Nb Niobium 41 -41NB(NB) 334.91 * 20	
Nd Neodymium 60 -60NB(ND) 463.42 492.45 15	15
Au 232.00 * 42	
Ni Nickel 28 -28NQ(NI) 341.48 10 Os Osmium 76 -76NU(OS) 305.86 15	15
Pb Lead 82 -82NQ(PB) 217.00 10	15
Pd Palladium 46 -46NQ(PD) 244.79 * 10	20
D. D. SOND(DD) 495.13 * 45	15
Pr Praseodymium 59 -59NB(PR) 513.34 15 Pt Platinum 78 -78NU(PT) 265.95 * 299.80 10	20
Rb Rubidium 37 -37NB(RB) 780.02 * 794.76 10	20

Element		Atomic	Type No.	Analytical line	Lamp current (mA)	
		number	(suffix)	(nm)	Тур.	Max.
Re	Rhenium	75	-75NB(RE)	346.05 * 346.47	20	25
Rh	Rhodium	45	-45NB(RH)	343.49 *	10	20
Ru	Ruthenium	44	-44NB(RU)	349.89 *	20	25
Sb	Antimony	51	-51NQ(SB)	217.58 * 231.15	10	15
Sc	Scandium	21	-21NB(SC)	390.74 391.18 *	10	15
Se	Selenium	34	-34NQ(SE)	196.03 *	20	25
Si	Silicon	14	-14NU(SI)	251.61 * 288.16	10	20
Sm	Samarium	62	-62NB(SM)	429.67 * 484.17	15	20
Sn	Tin	50	-50NQ(SN)	224.61 * 286.33	20	20
Sr	Strontium	38	-38NB(SR)	460.73 *	10	20
Ta	Tantalum	73	-73NU(TA)	271.47 * 275.83	10	20
Tb	Terbium	65	-65NB(TB)	431.88 432.64 *	15	15
Te	Tellurium	52	-52NQ(TE)	214.27 *	10	15
Ti	Titanium	22	-22NB(TI)	364.27 * 365.35	10	20
TI	Thallium	81	-81NU(TL)	276.78 * 377.57	7	10
Tm	Thulium	69	-69NB(TM)	371.79 * 410.58	10	15
٧	Vanadium	23	-23NB(V)	306.64 318.40 *	10	20
W	Tungsten	74	-74NU(W)	255.14 * 400.87	10	25
Υ	Yttrium	39	-39NB(Y)	410.23 * 412.83	15	15
Yb	Ytterbium	70	-70NB(YB)	346.43 398.79 *	10	10
Zn	Zinc	30	-30NQ(ZN)	213.86 * 307.59	7	15
Zr	Zirconium	40	-40NB(ZR)	360.12 * 468.78	20	20
D2	Hydrogen	1	-1DQ(D2)	240.00 (peak value)	30	35

●L733 SERIES (38 mm DIA.): MULTI-ELEMENT HOLLOW CATHODE LAMPS (11 LAMPS) ①

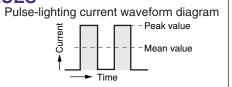
Element		Atomic Type No number (suffix)		Analytical line	Lamp current (mA)	
				(nm)	Тур.	Max.
Na-K	Sodium Potassium		-201NB	Na 589.00 * K 766.49 *	10	15
Ca-Mg	Calcium Magnesium	20 12	-202NU	Ca 422.67 * Mg 285.21 *	10	18
Si-Al	Silicon Aluminium	14 13	-203NU	Si 251.61 * Al 309.27 *	10	20
Fe-Ni	Iron Nickel	26 28	-204NQ	Fe 248.33 * Ni 232.00 *	10	20
Sr-Ba	Strontium Barium	26 28 38 56 13	-205NB	Sr 460.73 * Ba 553.55 *	10	20
Al-Ca-Mg	Aluminium Calcium Magnesium	20 12	-321NU	Al 309.27 * Ca 422.67 * Mg 285.21 *	10	18
Ca-Mg-Zn	Calcium Magnesium Zinc	20 12 30 29	-322NQ	Că 422.67 * Mg 285.21 * Zn 213.86 *	10	15
Cu-Mo- Co-Zn	Copper Molybdenum Cobalt Zinc	42 27 30	-401NQ	Cu 324.75 * Mo 313.26 * Co 240.73 * Zn 213.86 *	10	15
Cd-Cu- Pb-Zn	Cadmium Copper Lead Zinc	48 29 82 30	-402NQ	Cd 228.80 * Cu 324.75 * Pb 217.00 * Zn 213.86 *	10	15
Cu-Fe- Mn-Zn	Copper Iron Manganese Zinc	29 26 25 30 27	-405NQ	Cu 324.75 * Fe 248.33 * Mn 279.48 * Zn 213.86 *	8	15
Co-Cr-Cu- Fe-Mn-Ni	Cobalt Chromium Copper Iron Manganese Nickel	27 24 29 26 25 28	-601NQ	Co 240.73 * Cr 357.87 * Cu 324.75 * Fe 248.33 * Mn 279.48 * Ni 232.00 *	10	20

^{*} Analytical lines marked with an asterisk (*) indicate the maximum absorption wavelength of each element. Since each element has two or more spectral emission lines, select the appropriate spectral line for the sample concentration.

NOTE: ①The guaranteed life is defined by the product of the lamp current value (typ.) and the accumulated operating time and is specified as 5000 mA hrs except for the guaranteed life of As, Ga and Hg which are specified as 3000 mA hrs.

NOTE ON THE L233 AND L733 SERIES CURRENT VALUES

The lamp current values listed above are specified as a peak value. However, instruments using a pulse lighting system may indicate the lamp current value as the mean value. So, operate at the lamp current specified for the instrument in use.



LINEUP OF GIANT-PULSE HOLLOW CATHODE LAMPS

●L2433 SERIES (38 mm DIA.): SINGLE-ELEMENT HOLLOW CATHODE LAMPS (45 LAMPS)

Ag		Element	Atomic number	Type No. (suffix)	line		High current	Accumulated ② life (mA·ms·h)	Operating ^② life (h)
Al	Ag	Silver	47	-47NB(AG)	328.07 *			,	
As Arsenic 33 -33NQ(AS) 197.20 12 500 7500 150 Au Gold 79 -79NQ(AU) 242.80 10 400 20 000 500 B Boron 5 -5NQ(B) 249.67 10 500 5000 100 Ba Barium 56 -56NB(BA) 249.77 11 500 6000 100 Bi Bismuth 83 -83NQ(B) 323.06 10 300 6000 200 Ca Calcium 20 -20NU(CA) 422.67 15 600 30 000 500 Cd Cadmium 48 -48NQ(CD) 288.0 8 100 5000 500 Cd Cadmium 48 -48NQ(CD) 288.0 15 400 2000 500 Co Cobalt 27 -27NU(CO) 346.54 15 400 2000 500 Cr Chromium 24 -24NB(CR) 326.4 10 600 12000 200 Cu Copper 29 -29NB(CU) 327.40 10 500 25000 500 Er Erbium 68 -68NB(ER) 445.7 15 500 6000 100 Er Erbium 63 -63NB(EU) 46.57 15 500 6000 100 Eu Europium 63 -63NB(EU) 46.70 10 500 5000 100 Ga Gallium 31 -31NU(GA) 284.39 12 400 20 000 500 Ga Gallium 32 -32NU(GE) 263.10 20 500 5000 100 K Potassium 19 -19NB(K) 768.49 10 600 6000 100 K Potassium 19 -19NB(K) 768.49 10 600 6000 100 K Potassium 19 -19NB(K) 768.49 10 600 6000 100 K Potassium 19 -19NB(K) 768.49 10 600 6000 100 K Potassium 12 -12NU(MG) 266.47 20 600 9000 500 Mn Manganesse 25 -25NU(MM) 27.47 10 500 25 000 500 Mn Molybdenum 42 42NB(MO) 313.28 10 600 6000 100 Ru Ruthenium 46 -46NQ(PD) 247.70 10 500 25 000 500 Na Sodium 11 -11NB(NA) 588.59 10 600 30 000 500 Sh Sh Antimony 51 -51NU(SB) 283.00 10 500 500 Ru Ruthenium 46 -46NQ(PD) 247.70 10 500 25 000 500 Sh Samarium 24 -24NB(MO) 313.28 10 600 9000 150 Ru Ruthenium 46 -46NQ(PD) 247.70 10 500 25 000 500 Sh Antimony 51 -51NU(SB) 283.00 10 500 6000 100 Ru Ruthenium 47 -4NB(RU) 288.31 10 500 500 500 Sh Antimony 51 -51NQ(SB) 233.55 15 500 25 000 500 Sh Samarium 62 -62NB(SM) 428.77 15 600 6000 100 Sh Antimony 51 -51NQ(SB) 233.50 10 500 6000 100 Sh Antimony 51 -51NQ(SB) 283.50 10 500 25 000 500 Sm Samarium 62 -62NB(SM) 420.67 15 600 6000 100 Sh Antimony 52 -52NQ(TE) 366.35 10 600 1000 200 Sr Strontium 38 3NB(SR) 406.27 15 600 6000 100 Fe Tellurium 52 -52NQ(TE) 366.35 10 600 6000 100 Ti Titanium 22 -22NB(TI) 365.35 10 600 6000 100				, ,	309.27 *				
Au Gold 79 -79NQ(AU) 267.59 10 400 20 000 500				. ,	193.70 *				
B Boron 5 -5NQ(B) 249.77 10 500 5000 100				` ,	242.80 *				
Ba Barium 56 -56NB(BA) 583.55 * 15 600 30 000 500 Be Beryllium 4 -4NO(BE) 234.86 * 10 600 6000 100 Bi Bismuth 83 -83NQ(BI) 306.77 * 10 300 6000 200 Ca Calcium 20 -20NU(CA) 422.67 * 15 600 30 000 500 Co Cobalt 27 -27NU(CO) 346.58 * 15 400 2000 500 Cr Chromium 24 -24NB(CRI) 357.87 * 10 500 25 000 500 Dy Dysprosium 66 -66NB(EPI) 425.41 * 10 600 12 000 200 Er Erbium 68 -68NB(ERI) 415.11 * 15 500 500 100 Er Erbium 68 -68NB(ERI) 415.11 * 15 500 5000 100 Er Erb				, ,	249.68 *				
Be Beryllium 4 -4NO(BE) 234.86 10 600 6000 100				, ,					
Bi Bismuth 83 -83NQ(B) 300.77 10 300 6000 200 Ca Calcium 20 -20NU(CA) 422.67* 15 600 30 000 500 Cd Cadmium 48 -48NQ(CD) 228.80* 8 100 5000 500 Co Cobalt 27 -27NU(CO) 346.58 15 400 2000 500 Cr Chromium 24 -24NB(CR) 485.45* 10 600 12 000 200 Cu Copper 29 -29NB(CU) 327.45* 10 600 12 000 200 Dy Dysprosium 66 -66NB(EN) 400.79* 15 600 6000 100 Er Erbium 68 -68NB(ER) 400.79* 15 600 6000 100 Eu Europium 63 -63NB(EU) 499.40* 10 600 6000 100 Ga Gallium				, ,	234.86 *				
Ca Calcium 20 -20NU(CA) 482-67* 15 600 30 000 500 Cd Cadmium 48 -48NQ(CD) 228.80* 8 100 5000 500 Co Cobalt 27 -27NU(CO) 246.58* 15 400 2000 500 Cr Chromium 24 -24NB(CR) 357.87* 10 600 12 000 200 Cu Copper 29 -29NB(CU) 334.75* 10 600 12 000 200 Dy Dysprosium 66 -66NB(DY) 400.79* 15 600 6000 100 Er Erbium 68 -68NB(ER) 400.79* 15 500 5000 100 Eu Europium 63 -68NB(ER) 400.79* 15 500 5000 100 Fe Iron 26 -26NQ(FE) 246.33* 12 400 20 000 500 Ga Gallium				, ,					
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Cr Chromium 24 -24NB(CR) 457.97 1 0 600 12 000 200 Cu Copper 29 -29NB(CU) 324.75 10 500 25 000 500 Dy Dysprosium 66 -66NB(DY) 404.59 11 500 500 600 100 Er Erbium 68 -68NB(ER) 415.11 15 500 5000 100 Eu Europium 63 -63NB(EU) 469.07 10 600 6000 100 Fe Iron 26 -26NQ(FE) 271.99 12 400 20 000 500 Ga Gallium 31 -31NU(GA) 286.64 20 500 5000 100 Hf Hafnium 72 -72NU(HF) 307.29 20 600 6000 100 Ho Holmium 67 -67NB(HO) 410.38 10 600 600 500 La				, ,	240.73 *				
Cu Copper 29 -29NB(CU) 322/75 (a) 10 500 25 000 500 Dy Dysprosium 66 -66NB(DY) 404.59 (a) 15 600 6000 100 Er Erbium 68 -68NB(ER) 400.79 (a) 15 500 5000 100 Eu Europium 63 -63NB(EU) 459.40 (a) 10 600 6000 100 Fe Iron 26 -26NQ(FE) 273.71.99 (a) 12 400 20 000 500 Ga Gallium 31 -31NU(GA) 287.42 (a) 4 400 4000 100 Hf Hafnium 72 -72NU(HF) 286.64 (a) 20 500 5000 100 Ho Holmium 67 -67NB(HO) 410.30 (a) 10 600 6000 100 K Potassium 19 -19NB(K) 766.49 (a) 10 600 30 000 500 La				, ,	357.87 *				
Dy Dysprosium 66 -66NB(DY) 421,17 421,17 400,79 421,17 400,79 40				` '					
Er Erbium 68 -68NB(ER) 415.11 15 500 5000 100 Eu Europium 63 -63NB(EU) 469.40* 10 600 6000 100 Fe Iron 26 -26NQ(FE) 371.93* 12 400 20 000 500 Ga Gallium 31 -31NU(GA) 287.42* 4 400 4000 100 Ge Germanium 32 -32NU(GE) 286.61* 20 500 5000 100 Hf Hafnium 72 -72NU(HF) 307.29* 20 600 6000 100 Ho Holmium 67 -67NB(HO) 416.30* 10 600 6000 100 K Potassium 19 -19NB(K) 766.49* 20 600 9000 150 La Lanthanum 57 -57NB(LA) 550.13* 20 600 9000 150 Magnesium 12				, ,					
ET Ethium 68	-	,		. ,					
Eu Europitin 63 -03NB(EU) 462.72 10 600 6000 100				, ,	415.11	-			
Fe		· '		, ,	462.72				
Ga Gaillum 31 -51NU(GA) 294.36.* 4 400 4000 100 Hf Hafnium 32 -32NU(GE) 265.16.* 20 500 5000 100 Ho Holmium 67 -72NU(HF) 307.29.* 20 600 6000 100 K Potassium 19 -19NB(K) 766.49.* 10 600 30 000 500 La Lanthanum 57.57NB(LA) 357.44. 550.13.* 20 600 9000 150 Li Lithium 3 -3NB(LI) 610.36. 670.78.* 15 500 25 000 500 Mg Magnesium 12 -12NU(MG) 285.21.* 10 500 25 000 500 Mn Manganese 25 -25NU(MN) 493.08. 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 313.26.* 10 600 9000 150	-			,	371.99				
He				, ,	294.36 *				
Hi Hainlum 72 -72N(HF) 307.29 20 600 6000 100 Ho Holmium 67 -67NB(HO) 416.30 416.30 10 600 6000 100 K Potassium 19 -19NB(K) 768.49 768.99 10 600 30 000 500 La Lanthanum 57 -57NB(LA) 550.13 20 600 9000 150 Li Lithium 3 -3NB(LI) 670.78 15 500 25 000 500 Mg Magnesium 12 -12NU(MG) 285.21 10 500 25 000 500 Mn Manganese 25 -25NU(MN) 403.08 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 320.88 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.59 10 600 12 000 200 Ni Nickel 28 -28NQ(PB) 283.30 10 300 15 000 500 Pb Lead 82 -82NQ(PB) 283.30 10 300 3000 100 Pt Platinum 46 -46NQ(PD) 247.64 10 300 3000 100 Pt Platinum 44 -44NB(RU) 349.89 20 600 6000 100 Ru Ruthenium 44 -44NB(RU) 349.89 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 217.58 15 500 7500 150 Si Silicon 14 -14NU(SI) 288.16 10 500 500 250 Sr Strontium 38 -38NB(SR) 460.73 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27 15 400 4000 100 Ti Titanium 23 -23NB(V) 318.40 10 700 7000 100 Y Vttrium 39 -39NB(Y) 410.33 416.42 41			-	, ,					
Ho Holmlum 67 -67NB(HO) 416.30 10 600 6000 100 100	Hf	Hafnium	72	-72NU(HF)	307.29	20	600	6000	100
K Potassium 19 -19NB(N) 769.90 10 600 30 000 500 La Lanthanum 57 -57NB(LA) 357.444 20 600 9000 150 Li Lithium 3 -3NB(LI) 670.78* 15 500 25 000 500 Mg Magnesium 12 -12NU(MG) 285.21* 10 500 25 000 500 Mn Manganese 25 -25NU(MN) 279.48* 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 313.26* 320.88 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.59 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 341.48* 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 283.30 10 300 15 000 500 Pd <td>Но</td> <td>Holmium</td> <td>67</td> <td>-67NB(HO)</td> <td>416.30</td> <td>10</td> <td>600</td> <td>6000</td> <td>100</td>	Но	Holmium	67	-67NB(HO)	416.30	10	600	6000	100
La Lantmanum 57 -5/NB(LA) 550.13 * 20 600 9000 150 Li Lithium 3 -3NB(LI) 610.36 610.36 670.78 * 15 500 25 000 500 Mg Magnesium 12 -12NU(MG) 285.21 * 10 500 25 000 500 Mn Manganese 25 -25NU(MN) 403.08 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 313.26 * 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.00 * 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 232.00 * 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 283.30 10 300 15 000 500 Pd Palladium 46 -46NQ(PD) 241.70 * 10 300 3000 100 Pt Platinum 78 -78NU(PT) 265.95 * 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89 * 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 231.15 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03 15 300 4500 150 Si Silicon 14 -14NU(SI) 251.61 * 15 500 7500 150 Sm Samarium 62 -62NB(SM) 429.67 * 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27 * 15 400 4000 100 Ti Titanium 23 -23NB(V) 318.40 * 10 700 7000 100 Y Vanadium 23 -39NB(Y) 412.83 15 600 6000 100	K	Potassium	19	-19NB(K)	769.90	10	600	30 000	500
Mg Magnesium 12 -12NU(MG) 285.21	La	Lanthanum	57	-57NB(LA)	550.13 *	20	600	9000	150
Mg Magnesium 12 -12NO(MG) 10 500 25 000 500 Mn Manganese 25 -25NU(MN) 279.48 * 403.08 * 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 313.26 * 320.88 * 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.59 * 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 341.48 * 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 217.00 * 2	Li	Lithium	3	-3NB(LI)	670.78 *	15	500	25 000	500
Min Manganese 25 -25NU(MN) 403.08 10 600 30 000 500 Mo Molybdenum 42 -42NB(MO) 313.26 * 320.88 * 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.59 * 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 232.00 * 341.48 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 217.00 * 341.48 10 400 20 000 500 Pd Palladium 46 -46NQ(PD) 244.79 * 10 300 3000 100 Pt Platinum 78 -78NU(PT) 265.95 * 299.80 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89 * 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 217.58 * 231.15 * 15 500 7500 150 Se Selenium 34 -	Mg	Magnesium	12	-12NU(MG)		10	500	25 000	500
No Molybdenum 42 -42NB(MO) 320.88 10 600 9000 150 Na Sodium 11 -11NB(NA) 589.09 * 589.09 * 589.00 * 589.09 * 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 232.00 * 341.48 * 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 283.30 * 10 300 15 000 500 Pd Palladium 46 -46NQ(PD) 244.79 * 247.64 * 10 300 3000 100 Pt Platinum 78 -78NU(PT) 265.95 * 29.80 * 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89 * 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 231.15 * 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03 * 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61 * 20	Mn	Manganese	25	-25NU(MN)	403.08	10	600	30 000	500
Na Sodium 11 -11Nb(NA) 589.59 10 600 12 000 200 Ni Nickel 28 -28NQ(NI) 232.00* 10 400 20 000 500 Pb Lead 82 -82NQ(PB) 232.00* 10 300 15 000 500 Pd Palladium 46 -46NQ(PD) 244.79* 10 300 3000 100 Pt Platinum 78 -78NU(PT) 299.80* 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89* 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 217.58* 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03* 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61* 10 500 10000 200 Sm Samarium	Мо	Molybdenum	42	-42NB(MO)	320.88	10	600	9000	150
Nickel 28 -28NQ(Ni) 341.48 10 400 20 000 500	Na	Sodium	11	-11NB(NA)	589.59	10	600	12 000	200
Pb Lead 82 -82NQ(PB) 283.30 10 300 15 000 500 Pd Palladium 46 -46NQ(PD) 244.79* 10 300 3000 100 Pt Platinum 78 -78NU(PT) 265.95* 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89* 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 217.58* 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03* 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61* 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 489.67* 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61* 20 500 25 000 500 Sr Strontium	Ni	Nickel	28	-28NQ(NI)	341.48	10	400	20 000	500
Pd Palladium 46 -46NQ(PD) 247.64 10 300 3000 100 Pt Platinum 78 -78NU(PT) 265.95* 299.80 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89* 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 231.15* 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03* 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61* 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 429.67* 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61* 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73* 10 500 25 000 500 Te T	Pb	Lead	82	-82NQ(PB)	283.30	10	300	15 000	500
Pt Platinum 78 -78NO(P1) 299.80 10 300 3000 100 Ru Ruthenium 44 -44NB(RU) 349.89 * 20 600 6000 100 Sb Antimony 51 -51NQ(SB) 217.58 * 15 500 7500 150 Se Selenium 34 -34NQ(SE) 196.03 * 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61 * 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 429.67 * 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61 * 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 V Vanad	Pd	Palladium	46	-46NQ(PD)	247.64	10	300	3000	100
Sb	Pt	Platinum	78	-78NU(PT)	299.80	10	300	3000	100
Sb Affilinity 51 -5 INQ(SB) 231.15 15 300 7500 150 Se Selenium 34 -34NQ(SE) 196.03 * 15 300 4500 150 Si Silicon 14 -14NU(SI) 288.16 * 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 429.67 * 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61 * 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27 * 10 600 12 000 200 V Vanadium 23 -23NB(V) 318.40 * 10 700 7000 100 Y Ytt	Ru	Ruthenium	44	-44NB(RU)		20	600	6000	100
Se Selenium 34 -34NQ(SE) 15 300 4500 150 Si Silicon 14 -14NU(SI) 281.61 * 288.16 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 429.67 * 484.17 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61 * 286.33 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 Ti Titanium 22 -22NB(TI) 365.35 * 10 600 12 000 200 V Vanadium 23 -23NB(V) 318.40 * 10 700 7000 100 Yttrium 39 -39NB(Y) 410.23 * 412.83 15 600 6000 100	Sb	Antimony	51	-51NQ(SB)	231.15	15	500	7500	150
SI Silicon 14 -14NO(SI) 288.16 10 500 10 000 200 Sm Samarium 62 -62NB(SM) 429.67* 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61* 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73* 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27* 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27* 10 600 12 000 200 V Vanadium 23 -23NB(V) 306.64 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23* 15 600 6000 100	Se	Selenium	34	-34NQ(SE)		15	300	4500	150
Sm Samarium 62 -62NB(SM) 484.17 15 600 6000 100 Sn Tin 50 -50NQ(SN) 224.61* 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73* 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27* 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27* 10 600 12 000 200 V Vanadium 23 -23NB(V) 318.40* 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23* 15 600 6000 100	Si	Silicon	14	-14NU(SI)	288.16	10	500	10 000	200
Sil Till 50 -50NQ(SN) 286.33 20 500 25 000 500 Sr Strontium 38 -38NB(SR) 460.73 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27 * 10 600 12 000 200 V Vanadium 23 -23NB(V) 306.64 * 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23 * 15 600 6000 100	Sm	Samarium	62	-62NB(SM)		15	600	6000	100
Sr Strontium 38 -38NB(SR) 460.73 * 10 500 25 000 500 Te Tellurium 52 -52NQ(TE) 214.27 * 15 400 4000 100 Ti Titanium 22 -22NB(TI) 364.27 * 365.35 * 10 600 12 000 200 V Vanadium 23 -23NB(V) 306.64 * 318.40 * 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23 * 412.83 * 15 600 6000 100	Sn	Tin	50	-50NQ(SN)	224.61 * 286.33	20	500	25 000	500
Ti Titanium 22 -22NB(TI) 364.27 * 10 600 12 000 200 V Vanadium 23 -23NB(V) 306.64 318.40 * 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23 * 15 600 6000 100	Sr	Strontium	38	-38NB(SR)	460.73 *	10	500	25 000	500
V Vanadium 23 -23NB(V) 365.35 10 600 12 000 200 V Vanadium 23 -23NB(V) 306.64 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23* 15 600 6000 100	Te	Tellurium	52	-52NQ(TE)	214.27 *	15	400	4000	100
V Vanadium 23 -23NB(V) 306.64 318.40 * 10 700 7000 100 Y Yttrium 39 -39NB(Y) 410.23 * 412.83 15 600 6000 100	Ti	Titanium	22	-22NB(TI)		10	600	12 000	200
Y Yttrium 39 -39NB(Y) 410.23 * 15 600 6000 100	V	Vanadium	23	-23NB(V)	306.64	10	700	7000	100
246.42	Υ	Yttrium	39	-39NB(Y)	410.23 *	15	600	6000	100
Yb Ytterbium 70 -70NB(YB) 346.43 5 200 2000 100	Yb	Ytterbium	70	-70NB(YB)	346.43	5	200	2000	100
Zn Zinc 30 -30NQ(ZN) 213.86 * 10 300 15 000 500	Zn	Zinc	30	-30NQ(ZN)	213.86 *	10	300	15 000	500

* Analytical lines marked with an asterisk (*) indicate the maximum absorption wavelength of each element. Since each element has two or more spectral emission lines, select the appropriate spectral line for the sample concentration.

NOTE:

- ①See the current waveform charts for the low current and high current waveform specifications.
- ②The guaranteed life is specified by either of the definitions below.
- When lamps are operated at a current less than the lamp current value specified for each element:

The accumulated life (mA·ms·h) defined by the accumulated operating time including the lamp preheat time multiplied by the product of the low current and its time width or the product of the high current and its time width, whichever is larger.

 When lamps are operated at the lamp current value specified for each element:

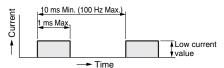
The accumulated operating time including the lamp preheat time.

NOTE ON L2433 SERIES -LAMP CURRENT VALUES

OLAMP CURRENT VALUE (LOW CURRENT)

Absorption of the target element occurs when a lamp is operated at a low current. Set the current so that the current value listed for the lamp is not exceeded.

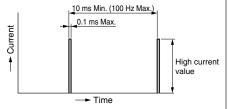
Current waveform chart



●LAMP CURRENT VALUE (HIGH CURRENT)

When a lamp is operated at a high current, a self-reversal effect occurs in the lamp to absorb the background. Set the current so that the current value listed for the lamp is not exceeded.

Current waveform chart



•TIME WIDTH

Do not operate the lamps in a state where the time width of the current waveform exceeds the maximum time width shown in the above charts.

LAMP CURRENT AND ABSORPTION SENSITIVITY

The ideal analytical line profile of the light emitted by a hollow cathode lamp should exhibit no spectral line broadening other than natural broadening. In actual operation, however, the spectral lines are emitted along with a broadening other than natural broadening. The causes of such broadening include Doppler broadening, self-absorption line width distortion, Lorentz broadening (pressure broadening), Holtzmark broadening (resonance broadening), Zeeman effect broadening, and Stark effect broadening. Among these, Doppler broadening and self-absorption line width distortion are major factors in broadening so that broadening related to other causes is usually small enough to be ignored.

Doppler broadening depends on the random thermal motion of the excited metal atoms, which is affected by the temperature of the gas. Spectral line broadening does not occur as long as the thermal motion of the atoms is perpendicular to a line connecting the observation point and the light emission point. However, if the thermal motion of the atoms is parallel to that line (forward and back motion as seen from the observation point), the frequency between the light emission point and observation point will increase (shift to shorter wavelength side) during motion toward the observation point and decrease (shift to longer wavelength side) during motion away from the observation point. This phenomenon is the so-called Doppler effect. Excited metal atoms in a cathode have a random thermal motion that causes the spectral lines to broaden. The width λ₀ of this Doppler broadening can be expressed by the following equation: !!! where c is the velocity of light, R is the gas constant, T is the absolute temperature of the gas, and Ma is the atomic weight.

$$\Delta\lambda_{\rm D}$$
=1.67 × $\frac{\lambda_0}{c}$ $\sqrt{\frac{2RT}{Ma}}$

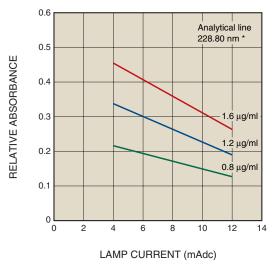
When there is a temperature gradient due to metal atoms flowing out of the hollow, higher-temperature metal atoms in the hollow are more excited than lower-temperature metal atoms outside the hollow, and so cause light emission. Self-absorption is a phenomenon in which this emitted light is absorbed as it passes through the relatively low-temperature metal atoms outside the hollow. Just as with the Doppler effect, this phenomenon results in broadening of analytical line width and a loss of absorption sensitivity.

As stated above, deterioration in the analytical line profile depends on the lamp current, so care must be taken since increasing the lamp current may cause an excessive increase in metal atoms. In actual measurement, it is essential to operate the lamp at an optimal lamp current that takes into account both the analytical line output intensity and absorption sensitivity.

The self-absorption effect is large for high-vaporization-pressure elements such as Cd (Cadmium) and small for low-vaporization-pressure elements such as Mo (Molybdenum). The lamp current for the former is usually specified as a low value.

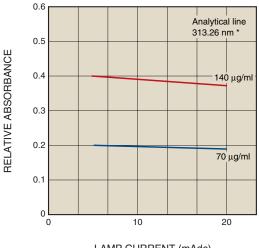
Figure 3: Lamp current vs. absorption sensitivity (Typ.)

●L233-48NQ (CD)



^{*} Maximum absorption wavelength

●L233-42NB (MO)

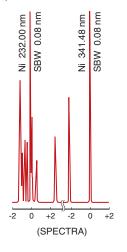


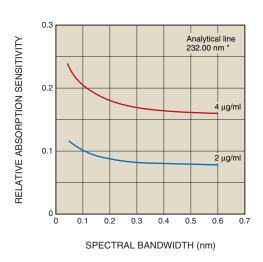
SPECTRAL BANDWIDTH (S.B.W.) AND ABSORPTION SENSITIVITY

In the vicinity of an analytical line, the presence of other spectral lines from the same element or a different element will cause the absorption sensitivity to drop. (These spectral lines in the vicinity of the analytical line are known as proximity lines.) When these proximity lines are present, the spectral bandwidth (SBW) should be narrowed to reduce the effect of proximity lines by narrowing the slit width of the spectrophotometer.

Figure 4: Spectral bandwidth and absorption sensitivity (Typ.)

●L233-28NQ (NI)





^{*} Maximum absorption wavelength

TIME STABILITY OF ANALYTICAL LINE RADIANT INTENSITY

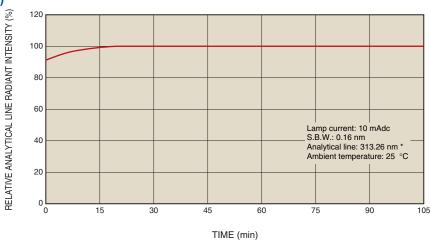
As described in the section dealing with the emission process, sputtered metal atoms are thermally diffused during repeated inelastic collisions with electrons. During the period required for the metal atom density to reach equilibrium, the radiant intensity of the analytical lines varies. This variation usually occurs in the direction of increased intensity for 10 to 20 minutes after the lamp has started, although it will vary depending on the element and lamp current. After reaching equilibrium, the radiant intensity at the analytical line is extremely stable. In high-vapor-pressure element lamps, operation at excessive lamp current levels causes excessively increased metal atoms to flow out of the hollow cathode space in the direction of the optical axis. This might lower the analytical line radiant intensity due to phenomena such as self-absorption.

cathode space in the direction of the optical axis. This might lower the analytical line radiant intensity due to phenomena such as self-absorption.

After a lamp has been left unused for a long period of time, some amount of time may be required for analytical line radiant intensity to reach initial stabilization, which results from changes in the cathode surface over time and depends on the element (especially alkaline element). Even in such cases, once the lamp is operated, it will light up normally from the next time.

Figure 5: Time stability of analytical line radiant intensity (Typ.)

●L233-42NB (MO)



^{*} Maximum absorption wavelength

LIFE

The life of a hollow cathode lamp is greatly affected by the lamp current. This is due to the increase in the energy of positive ions colliding with the cathode surface which causes violent sputtering. During pulse operation as well, there is no change in the energy of the positive ions colliding with the cathode surface at each pulse, so lamp life is determined by the peak current and the pulse width (time width).

The following phenomena may be observed when a lamp has reached its life end:

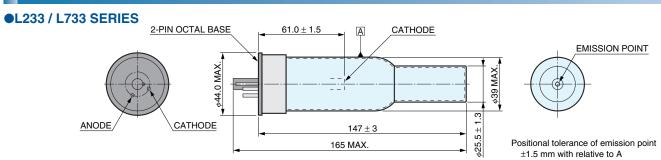
- (1) The lamp does not emit light, and the lamp current does not vary even if the current control knob is changed. The analytical line output is not detectable.
- (2) Extreme variations occur in analytical line radiant intensity and the lamp current may also vary in some cases.
- (3) The analytical line radiant intensity weakens significantly and the signal-to-noise ratio deteriorates.

These phenomena are mainly caused by a drop in gas pressure within the lamp, which is due to a "gas clean-up" phenomenon in which sputtered metal atoms attract gases while being scattered and adhere to the bulb wall and electrodes at a lower temperature.

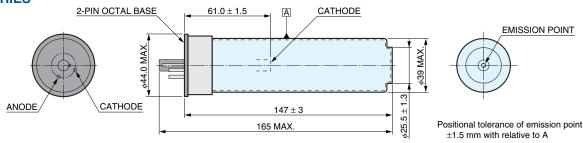
As the lamp is used, the cathode is gradually worn away and deformed by sputtering.

These characteristics will vary depending upon the element and will exhibit small differences even for lamps of the same element.

DIMENSIONAL OUTLINES (Unit: mm)







RELATED PRODUCTS

DEUTERIUM LAMPS (L2D2® LAMPS)

L2D2 lamps are deuterium lamps developed for spectrophotometry for chemical analysis.

These L2D2 lamps offer long life, high stability, and the high output needed for light sources used in spectrophotometry. L2D2 lamps can also be used for background correction in atomic absorption spectrophotometers.



PHOTOMULTIPLIER TUBES

Among the many light sensors currently available, photomultiplier tubes are the most sensitive and photodetectors with high speed response.

Photomultiplier tubes are designed and manufactured to provide stable operation even when detecting changes in weak light or its on/off, or even when the supply voltage is varied. These features make photomultiplier tubes useful as a photodetectors that ensure accurate measurements in atomic absorption spectroscopy.



PRECAUTIONS AND WARRANTY

■PRECAUTIONS

1. LONG-TERM STORAGE

Please note that the lamps should be used shortly after delivery. If the lamps are left unused for a long period of 6 months or more, take the following precautions:.

- · Store the lamps in low humidity and at room temperature in locations where no corrosive gases are present and temperature fluctuations are
- · We recommend operating the lamp for approximately 3 hours once every 3 months at half the listed lamp current in order to stabilize the lamp characteristics.

2. HANDLING

- · High voltage is supplied to the lamp to start operation. Take precautions to avoid electrical shock.
- · Ultraviolet rays harmful to the eyes and skin are emitted from the lamp window during operation. Do not look directly at the operating lamp.
- · Disposal of hollow cathode lamps

The cathode of some hollow cathode lamps contains elements that are defined as hazardous substances under waste disposal laws. When disposing of the lamps using such as the cathode, entrust proper disposal to an industrial waste disposal company licensed to perform intermediate treatment and final disposal of hazardous substances. Lamps using a cathode that does not contain the following elements may be disposed of as normal industrial waste (like glass and ceramic waste). Even in such cases, be sure to comply with local regulations to ensure correct disposal.

Elements of hazardous substance: As, Be, Cd, Cr, Cs, Cu, Hg, In, K, Na, Ni, Pb, Rb, Se, V, Zn, Na-K

Do not touch the lamp window with bare hands. Grime from the hands adhering to the window will cause a drop in the analytical line radiant intensity. If you touch the lamp, wipe the window using gauze or oil-free cotton moistened with high-purity alcohol and wrung out thoroughly.

Note that the volatile vaporization of organic solvents will absorb analytical lines of As, Se, etc. So use caution when handling such solvents near the measurement site.

The bulb wall or electrodes of some lamps might appear in a blackened state when delivered. This is caused by the spattering of cathode materials and this condition will differ depending on the particular element. This condition is especially noticeable on lamps with high vapor pressure elements such as As, Se, Cd, Zn, Na and K. This condition occurs during the manufacturing process and does not affect the lamp operating characteristics.

- · The major analytical lines used in atomic absorption spectroscopy are present in the UV wavelength range from 200 nm to 300 nm. Since mirrors, lenses and other optical components generally have low reflection or transmission efficiency in this wavelength region, alternately fine-adjust the spectrophotometer wavelength dial and the lamp position so that the output meter indicates the maximum while checking the wavelength dial scale to achieve the correct analytical line. Failure to make this analytical line adjustment correctly may prevent obtaining high measurement accuracy.
- If a high current is passed through the lamp suddenly when lighting the lamp or the power supply is cut off suddenly when the lamp is lit, surge currents or other abnormal currents will flow in the lamp, causing unnecessary lamp deterioration. When lighting the lamp, gradually increase the lamp current to the specified value and when turning off the lamp, also gradually decrease the current to ensure a long lamp life with stable operation.
- · The lamp current (max.) shown on the lamp is the absolute maximum value (which is broadly viewed as the guaranteed current at which no damage is caused to the lamp). In lamps based on elements having high vapor pressure (e.g., Hg, Cd and Zn), the maximum current shown on the lamp is set to a low lamp current value. If operated at a current higher than this value, the resulting Joule heat might melt the cathode.

■WARRANTY

WARRANTY PERIOD

Hamamatsu hollow cathode lamps are warranted for a period of one year after the date of delivery.

WARRANTY COVERAGE

The warranty is limited to repair or replacement of defective lamps free of charge.

CASES NOT COVERED BY WARRANTY

The warrant shall not apply to the following cases even if within the warranty period.

- · Lamp operation has exceeded the guaranteed life.
- · Lamp failure was caused by incorrect usage that did not meet the product specifications or by careless handling or modifications made by
- · Lamp failure was caused or induced by unavoidable accidents such as natural disasters.
- * L2D2 is registered trademark of Hamamatsu Photonics K.K.
- Subject to local technical requirements and regulations, availability of products included in this promotional material may vary. Please consult with our sales office.
- Information furnished by HAMAMATSU is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omissions. Specifications are subject to change without notice. No patent rights are granted to any of the circuits described herein. ©2017 Hamamatsu Photonics K.K.

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